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Inventor Name Search Result

Your Search was:

Last Name = SAKURADA

First Name = MASAHIRO

Application#	Patent#	Status	Date Filed	Title	Inventor Name
<u>08498894</u>	<u>5609682</u>	150	07/06/1995	A METHOD FOR THE PREPARATION OF SILICON SINGLE CRYSTAL	SAKURADA, MASAHIRO
<u>08565100</u>	<u>5667584</u>	150	11/30/1995	METHOD FOR THE PREPARATION OF A SINGLE CRYSTAL OF SILICON WITH DECREASED CRYSTAL DEFECTS	SAKURADA, MASAHIRO
<u>08655810</u>	<u>5817171</u>	150	05/31/1996	APPARATUS AND METHOD FOR PRODUCING SINGLE CRYSTAL USING CZOCHRALSKI TECHNIQUE	SAKURADA, MASAHIRO
<u>08660198</u>	<u>5728211</u>	250	06/03/1996	SILICON SINGLE CRYSTAL WITH LOW DEFECT DENSITY AND METHOD OF PRODUCING SAME	SAKURADA, MASAHIRO
<u>08666654</u>	<u>5704973</u>	150	06/18/1996	AN APPARATUS AND METHOD FOR THE UNIFORM DISTRIBUTION OF CRYSTAL DEFECTS UPON A SILICON SINGLE CRYSTAL	SAKURADA, MASAHIRO
<u>08768282</u>	<u>5730800</u>	150	12/17/1996	FUSED SILICA GLASS CRUCIBLE	SAKURADA, MASAHIRO
<u>08798472</u>	<u>5948163</u>	250	02/10/1997	APPARATUS FOR MANUFACTURING CRYSTALS ACCORDING TO THE CZOCHRALSKI METHOD, AND CRYSTALS MANUFACTURED BY THE MANUFACTURING METHOD	SAKURADA, MASAHIRO
<u>09090400</u>	<u>5938842</u>	150	06/04/1998	METHOD FOR PRODUCING A SINGLE CRYSTAL USING	SAKURADA, MASAHIRO

				CZOCHRALSKI TECHNIQUE	
<u>09125339</u>	<u>6071337</u>	150	08/13/1998	APPARATUS AND METHOD FOR PRODUCING CRYSTALS BY THE CZOCHRALSKI METHOD AND CRYSTALS PRODUCED BY THIS METHOD	SAKURADA, MASAHIRO
<u>09232561</u>	<u>6174364</u>	150	01/15/1999	METHOD FOR PRODUCING SILICON MONOCRYSTAL AND SILICON MONOCRYSTAL WAFER	SAKURADA, MASAHIRO
<u>09328278</u>	<u>6190452</u>	150	06/08/1999	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR PRODUCING IT	SAKURADA, MASAHIRO
<u>09646713</u>	<u>6565822</u>	150	09/21/2000	EPITAXIAL SILICON WAFER, METHOD FOR PRODUCING THE SAME AND SUBSTRATE FOR EPITAXIAL SILICON WAFER	SAKURADA, MASAHIRO
<u>09727275</u>	<u>6482260</u>	150	11/30/2000	SILICON SINGLE CRYSTAL WAFER AND A METHOD FOR PRODUCING IT	SAKURADA, MASAHIRO
<u>10204935</u>	<u>6913646</u>	150	08/27/2002	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR PRODUCING SILICON SINGLE CRYSTAL	SAKURADA, MASAHIRO
<u>10312921</u>	<u>6893499</u>	150	12/26/2002	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR MANUFACTURING THE SAME	SAKURADA, MASAHIRO
<u>10500580</u>	<u>7129123</u>	150	07/01/2004	AN SOI WAFER AND A METHOD FOR PRODUCING AN SOI WAFER	SAKURADA, MASAHIRO
<u>10512470</u>	<u>7294196</u>	150	10/26/2004	A SILICON SINGLE CRYSTAL WAFER, AN EPITAXIAL WAFER AND A METHOD FOR PRODUCING A SILICON SINGLE CRYSTAL	SAKURADA, MASAHIRO
<u>10516347</u>	<u>7258744</u>	150	11/30/2004	GRAPHITE HEATER FOR PRODUCING SINGLE CRYSTAL, APPARATUS FOR PRODUCING SINGLE CRYSTAL, AND METHOD FOR PRODUCING SINGLE CRYSTAL	SAKURADA, MASAHIRO
<u>10530557</u>	Not	95	04/07/2005	ANNEALED WAFER AND	SAKURADA,

	Issued			METHOD FOR MANUFACTURING THE SAME	MASAHIRO
10538878	7214268	150	06/14/2005	METHOD OF PRODUCING P-DOPED SILICON SINGLE CRYSTAL AND P-DOPED N-TYPE SILICON SINGLE CRYSTAL WAFER	SAKURADA, MASAHIRO
10542376	Not Issued	71	07/14/2005	AN SOI WAFER AND A METHOD FOR PRODUCING THE SAME	SAKURADA, MASAHIRO
10546693	Not Issued	61	08/22/2005	An soi wafer and a method for producing the same	SAKURADA, MASAHIRO
10560581	Not Issued	71	02/02/2006	Method for producing a single crystal and a single crystal	SAKURADA, MASAHIRO
10561205	Not Issued	93	02/03/2006	A METHOD FOR PRODUCING A SINGLE CRYSTAL AND A SINGLE CRYSTAL	SAKURADA, MASAHIRO
10561865	7226507	150	02/20/2006	METHOD FOR PRODUCING SINGLE CRYSTAL AND SINGLE CRYSTAL	SAKURADA, MASAHIRO
11664436	Not Issued	20	03/30/2007	Apparatus for Producing a Single Crystal	SAKURADA, MASAHIRO

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